

 INFORMATION DISCLOSURE CITATION <small>(Use several sheets if necessary)</small>				ATTY DOCKET NO. ITO.0045US (P16093)		SERIAL NO. 10/634,130	
				APPLICANT(S): Brian G. Johnson et al.			
				FILING DATE: August 4, 2003	GROUP ART UNIT:		
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EXAMINER		DATE CONSIDERED 12/23/05					

*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

INFORMATION DISCLOSURE CITATION (Use several sheets if necessary)		ATTY DOCKET NO. ITO.0045US (P16093)	SERIAL NO. 10/634,130
		APPLICANT(S): BRIAN G. JOHNSON AND STEPHEN J. HUDGENS	
		FILING DATE: August 4, 2003	GROUP ART UNIT: 2651

U.S. PATENT DOCUMENTS

*EXAMINER INITIAL		DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE
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	B.						
	C.						

FOREIGN PATENT DOCUMENTS

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EXAMINER

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